

# GH5C105D3A/GH5C105D3B

Compact Size, Low Current Drive Hologram Laser  
for X8 to X12 Speed CD-ROM Drive(3-beam)

## ■ Features

- (1) With built-in high speed OPIC\*(TYP.20MHz) for ×8 to ×12 speed CD-ROM drive
- (2) Enables to design compact pick-up thanks to compact package(Thickness: 4.8mm)
- (3) Voltage output type(External noise solution is unnecessary.)
- (4) Low current drive(Operating current:TYP.18mA)
- (5) Maximum optical power output : 4.3mW\*1
- (6) Wavelength : 780nm

\*OPIC : (Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

## ■ Model No.

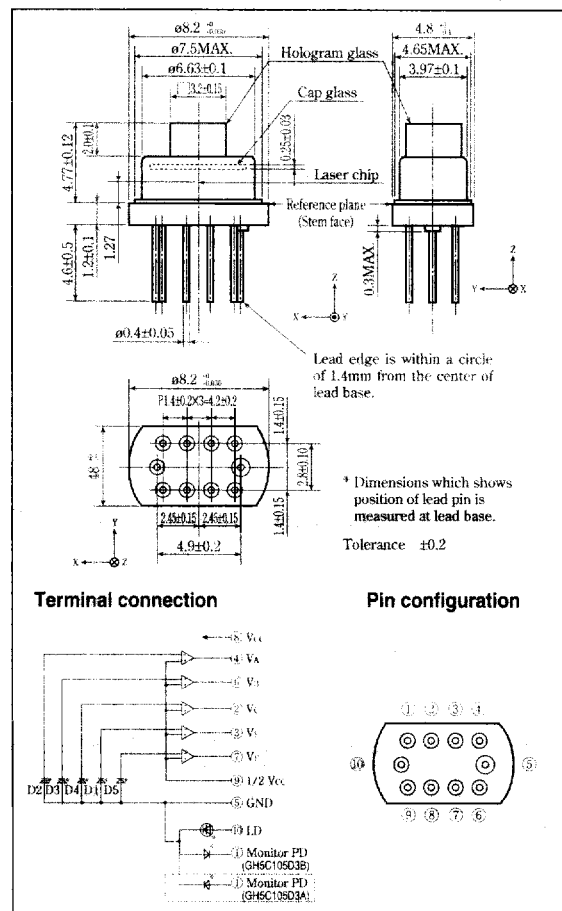
- (1) GH5C105D3A Dual power supply
- (2) GH5C105D3B Single power supply

## ■ Applications

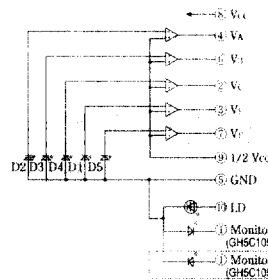
- (1) ×8 to ×12 speed CD-ROM drives
- (2) CD players etc.

## ■ Outline Dimensions

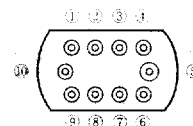
(Unit : mm)



### Terminal connection



### Pin configuration



## ■ Absolute Maximum Ratings

(T<sub>c</sub>=25°C)

Parameter	Symbol	Rating	Unit	
*1 Optical power output	P <sub>H</sub>	4.3	mW	
Reverse voltage	V <sub>R</sub>	Laser	2	V
		Monitor photodiode	30	V
OPIC supply voltage	V <sub>CC</sub>	6	V	
*2 Operating temperature	T <sub>opr</sub>	-10 to +60	°C	
*2 Storage temperature	T <sub>slg</sub>	-40 to +85	°C	
*3 Soldering temperature	T <sub>sold</sub>	260(5s to less)	°C	

\*1 Output power from hologram laser

\*2 Case temperature

\*3 At the position of 1.6mm or more from the lead base

**SHARP**

## ■ Electro-optical Characteristics

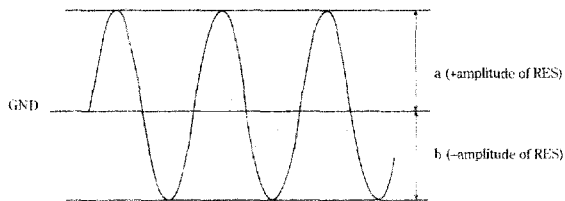
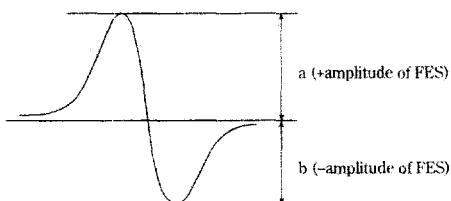
(V<sub>CC</sub>=5V, T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
*1 Focal offset	DEF	V <sub>RF</sub> =0.75V	-0.7	-	+0.7	μm	
*2 Focal error symmetry	B <sub>FES</sub>	V <sub>RF</sub> =0.75V	-25	-	+25	%	
*3 Radial error balance	B <sub>RES</sub>	V <sub>RI</sub> =0.75V	-25	-	+25	%	
*4 RF output amplitude	V <sub>RF</sub>	P <sub>H</sub> =3.0mW	0.53	1.20	2.10	V <sub>pp</sub>	
*5 FES output amplitude	V <sub>FES</sub>	V <sub>RF</sub> =0.75V	0.31	0.47	0.64	V <sub>pp</sub>	
	I <sub>FES</sub>						
*6 RES output amplitude	V <sub>RES</sub>	V <sub>RF</sub> =0.75V	0.12	0.21	0.29	V <sub>pp</sub>	
	I <sub>RES</sub>						
Threshold current	I <sub>th</sub>	-	-	13	18	mA	
Operating current	I <sub>op</sub>	P <sub>H</sub> =2.7mW	-	18	22	mA	
Operating voltage	V <sub>od</sub>	P <sub>H</sub> =2.7mW	-	1.8	2.2	V	
Wavelength	λ <sub>D</sub>	P <sub>H</sub> =2.7mW	770	780	795	nm	
Monitor current	I <sub>m</sub>	P <sub>H</sub> =2.7mW, V <sub>R</sub> =15V	GH5C105D3A	0.048	0.13	0.24	mA
			GH5C105D3B	0.021	0.6	0.11	
Differential efficiency	η	1.8mW I(2.7mW)-I(0.9mW)		-	0.65	-	mW/mA
Coherence	γ	P <sub>0</sub> =1.5mW		-	-	0.95	-

\*1 Distance between FES=0 and jitter minimum point  
At the condition of FES sensitivity = 20%/1μm

\*2 (a-b) / (a+b)

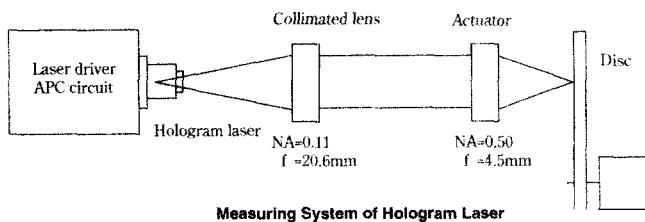
$$*3 \frac{a-b}{2 \times (a+b)}$$



\*4 Amplitude of V<sub>A</sub>+V<sub>a</sub>+2V<sub>C</sub> (focal servo ON, radial servo ON)

\*5 V<sub>E</sub>-V<sub>A</sub> (Focal vibration)

\*6 V<sub>E</sub>-V<sub>F</sub> (focal servo ON, radial servo OFF)



■ Electro-optical Characteristics of Laser Diode (Design Standard)

(Tc=25°C)

Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Radiation characteristics	Symmetry	Parallel	S <sub>  </sub>	Po=3mW, into NA=0.11	-25	-	+25	%
		Perpendicular	S <sub>⊥</sub>		-15	-	+15	%
Emission point accuracy	Position		Δx	-	-80	-	+80	μm
			Δy	-	-80	-	+80	μm
			Δz	-	-80	-	+80	μm

■ Electrical Characteristics of Monitor Photodiode (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*7 Sensitivity	S	V <sub>R</sub> =15V	-	0.048	-	mA/mW
Dark current	I <sub>d</sub>	V <sub>R</sub> =15V	-	-	150	nA
Terminal capacitance	C <sub>t</sub>	V <sub>R</sub> =15V	-	3.5	-	pF

\*7 For hologram output power

■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard)

(Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	** Segment	
Supply voltage	V <sub>cc</sub>		2.5	-	5.5	V	-	
Supply current	I <sub>cc</sub>	V <sub>cc</sub> =2.5V	2	5	10	mA	-	
*9 Output off-set voltage	V <sub>OD</sub>	V <sub>cc</sub> =2.5V, No light	-25	0	+25	mV	V <sub>A</sub> to F	
Off-set voltage difference	ΔV <sub>OD</sub>		-25	0	+25	mV	V <sub>A</sub> ,V <sub>B</sub> ,V <sub>C</sub> ,V <sub>E</sub> ,V <sub>F</sub>	
Response frequency	f <sub>CF</sub>	+10 V <sub>cc</sub> =5V, -3dB	3	5	-	MHz	V <sub>A</sub> ,V <sub>B</sub> ,V <sub>C</sub>	
	f <sub>CR</sub>	+10 V <sub>cc</sub> =5V, -3dB	0.2	0.7	-	MHz	V <sub>E</sub> ,V <sub>F</sub>	
Temperature coefficient of sensitivity	R <sub>ph</sub>	T <sub>a</sub> =20 to +70°C	-	1660	-	-	ppm/°C	V <sub>A</sub> ,V <sub>B</sub> ,V <sub>C</sub>
			-	1422	-	-		V <sub>E</sub> ,V <sub>F</sub>

\*\* Applicable divisions correspond to pattern segment No.

\*9 Difference from V<sub>cc</sub>/2

\*10 Output amplitude=0dB(input signal 100kHz)

Segment No.		output
D1	.....	V <sub>E</sub>
D2	.....	V <sub>A</sub>
D3	.....	V <sub>B</sub>
D4	.....	V <sub>C</sub>
D5	.....	V <sub>F</sub>

